NOV U 6 2006 BY

10/804578

PATENT

## THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inventor(s): Gonzalez et al.

Patent No.: 7,060,599 B2

**Issued:** June 13, 2006

For: METHOD OF FORMING SHALLOW

DOPED JUNCTIONS HAVING A

VARIABLE PROFILE GRADATION OF

DOPANTS (as amended)

Attorney Docket No.: 2269-7014.4US

CERTIFICATE OF MAILING

I hereby certify that this correspondence along with any attachments referred to or identified as being attached or enclosed is being deposited with the United States Postal Service as First Class Mail on the date of deposit shown below with sufficient postage and in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

November 2, 2006

Sig

Shawnee MacDonald

Name (Type/Print)

## REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT FOR APPLICANTS' MISTAKES (37 C.F.R. § 1.323) AND PATENT OFFICE MISTAKES (37 C.F.R. § 1.322)

Attn.: Certificate of Corrections Branch

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Certificate

NOV 0 8 2006

of Correction

Sir:

It is noted that a combination of Applicant and Patent Office errors appear in this patent of a typographical nature or character and correction thereof does not involve such changes in the patent as would constitute new matter or would require reexamination. A certificate of correction in the form attached hereto is requested.

Please send the Certificate to:

Address:

Name: Katherine A. Hamer

TraskBritt

P.O. Box 2550

Salt Lake City, Utah 84110

11/07/2006 MBIZUNES 00000037 7060599 01 FC:1811

100.00 np

The fee of \$100.00 as required by 37 C.F.R. § 1.20(a) is enclosed.

Attached hereto in duplicate is Form PTO/SB/44 with at least one copy being suitable for printing.

Respectfully submitted,

Katherine A. Hamer Registration No. 47,628

Attorney for Applicant(s)

TRASKBRITT P.O. Box 2550

Salt Lake City, Utah 84110-2550

Katherine A. Haver

Telephone: 801-532-1922

Date: November 2, 2006

KAH/slm

Enclosures: PTO/SB/44 in duplicate

Check No. 23251 in the amount of \$100.00

Document in ProLaw

## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. :

7,060,599 B2

Page 1 of 1

DATED

June 13, 2006

INVENTOR(S):

Fernando Gonzalez and Randhir Thakur

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page:

In the section (56) References Cited:

OTHER PUBLICATIONS

delete second occurrence of "Shu Qin, et al., "Plasma

Immersion Ion Implantation Doping Experiments for Microelectronics," pp. 962-968, J. Vac. Sci. Technol. B

12(2), Mar./Apr. 1994."

In the specification:

COLUMN 2, LINE 42,

change "modem integrated circuit" to --modern integrated

circuit--

COLUMN 6, LINE 32,

after "portion" insert --28--

In the claims:

CLAIM 3, COLUMN 8, LINE 21,

change "1750 Å from" to --1750 Å from--

MAILING ADDRESS OF SENDER:

PATENT NO. <u>7,060,599 B2</u>

No. of additional copies

Katherine A. Hamer 230 South 500 East, Suite 300 Salt Lake City, Utah 84102 USA

This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Attention Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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